Shedding new light on nanolasers using 2-D semiconductors

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In Ning’s experiment, the team measured optical gain at density levels four to five orders of magnitude—10,000 to 100,000 times—smaller than those in conventional semiconductors that power optoelectronic devices, like barcode scanners and lasers used in telecommunications tools.

Ning has been driven to make such a discovery by his interest in a phenomenon called the Mott transition, an unresolved mystery in physics about how excitons form trions and conduct electricity in semiconductor materials to the point that they reach the Mott density (the point at which a semiconductor changes from an insulator to a conductor and optical gain first occurs).

But the electrical power needed to achieve Mott transition and density is far more than what is desirable for the future of efficient computing. Without new low-power nanolaser capabilities like the ones he is researching, Ning says it would take a small power station to operate one supercomputer.

"If optical gain can be achieved with excitonic complexes below the Mott transition, at low levels of power input, future amplifiers and lasers could be made that would require a small amount of driving power," Ning says.

This development could be game-changing for energy-efficient photonics, or light-based devices, and provide an alternative to conventional semiconductors, which are limited in their ability to create and maintain enough excitons.

As Ning observed in previous experiments with 2-D materials, it is possible to achieve optical gain earlier than previously believed. Now he and his team have uncovered a mechanism that could make it work.

"Because of the thinness of the materials, electrons and holes attract each other hundreds of times
stronger than in conventional semiconductors," Ning says. "Such strong charge interactions make excitons and trions very stable even at room temperatures."

This means the research team could explore the balance of the electrons, holes, excitons and trions as well as control their conversion to achieve optical gain at very low levels of density.

"When more electrons are in the trion state than their original electron state, a condition called population inversion occurs," Ning says. "More photons can be emitted than absorbed, leading to a process called stimulated emission and optical amplification or gain."

In research conducted by Cun-Zheng Ning and his ASU and Tsinghua University collaborators, a single layer of 2D material was placed on a carefully designed substrate with gold as a back-gate to control the number of electrons in the material. Another laser pumps the 2D material to create excitons, some of which form trions with the pre-existing electrons. The reflected light is monitored to find the signature of amplification. Credit: Cun-Zheng Ning

Solving nanolaser mysteries, one step of fundamental science at a time

While this new discovery added a piece to the Mott transition puzzle—it uncovered a new mechanism that researchers can exploit to create low-power 2-D semiconductor nanolasers—Ning says that they are not yet sure if this is the same mechanism that led to the production of their 2017 nanolasers.

Work is still ongoing in resolving the remaining mysteries.

Similar trion experiments were conducted in the 1990s with conventional semiconductors, Ning says, "but the excitons and trions were so unstable, both experimental observation and, especially, utilization of this optical gain mechanism for real devices are extremely difficult."

"Since the excitons and trions are much more stable in the 2-D materials, there are new opportunities to make real-world devices out of these observations."

This interesting development by Ning and his research team is only at the fundamental science level. However, fundamental research can lead to exciting things.

"Basic science is a worldwide endeavor and everyone benefits if the best people from everywhere can be involved. ASU has provided an open and free environment, especially for international collaborations with top research groups in China, Germany, Japan and worldwide," Ning says.

His team has more work left to do to study how this new mechanism of optical gain works at different temperatures—and how to use it to create the nanolasers purposefully.

"The next step is to design lasers that can operate specifically using the new mechanisms of optical gain," Ning says.

With the physics foundations laid, they could eventually be applied to create new nanolasers that could change the future of supercomputing and data centers.

"The long-term dream is to combine lasers and electronic devices in a single integrated platform, to enable a supercomputer or data center on a chip," Ning says. "For such future applications, our present semiconductor lasers are still too large to be integrated with electronic devices."

More information: Zhen Wang et al, Excitonic
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